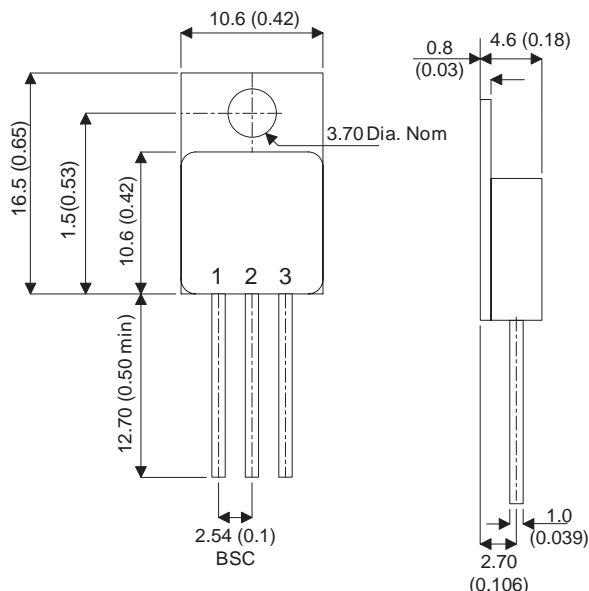


Dimensions in mm (inches).



N-Channel MOSFET in a Hermetically sealed TO257AB Metal Package.

$$V_{DSS} = 400V$$

$$I_D = 8.7A$$

$$R_{DS(ON)} = 0.55\Omega$$

All Semelab hermetically sealed products can be processed in accordance with the requirements of BS, CECC and JAN, JANTX, JANTXV and JANS specifications.

TO257AB (TO220M)

PINOUTS

1 – Gate 2 – Drain Case – Source

	Parameter	Min.	Typ.	Max.	Units
V_{DSS}	Drain – Source Breakdown Voltage			400	V
I_D	Continuous Drain Current			8.7	A
P_D	Power Dissipation			100	W
$R_{DS(ON)}$	Static Drain – Source On–State Resistance			0.55	Ω
C_{ISS}	Input Capacitance		1400		pF
Q_g	Total Gate Charge			65	nC
$t_{td(on)}$	Turn–On Delay Time			25	ns
t_{tr}	Rise Time			92	ns
$t_{td(off)}$	Turn–Off Delay Time			79	ns
t_f	Fall Time			58	ns

This is a shortform datasheet. For a full datasheet please contact sales@semelab.co.uk.

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use.